



DC/DC Converter Applications

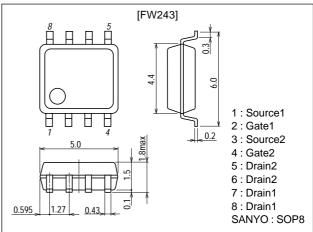
Features

- · Low ON resistance.
- · 4V drive.

Package Dimensions

unit:mm

2129



Specifications

Absolute Maximum Ratings at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|---|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | 30 | V |
| Gate-to-Source Voltage | VGSS | | ±20 | V |
| Drain Current (DC) | ID | | 7 | Α |
| Drain Current (pulse) | I _{DP} | PW≤10µs, duty cycle≤1% | 52 | Α |
| Allowable Power Dissipation | PD | Mounted on a ceramic board (1000mm²×0.8mm) 1unit | 1.7 | W |
| Total Dissipation | PT | Mounted on a ceramic board (1000mm ² ×0.8mm) | 2.0 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|---|---------|-----|-----|------|
| | | | min | typ | max | |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | I _D =1mA, V _{GS} =0 | 30 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | V _{DS} =30V, V _{GS} =0 | | | 1 | μA |
| Gate-to-Source Leakage Current | IGSS | V_{GS} =±16V, V_{DS} =0 | | | ±10 | μΑ |
| Cutoff Voltage | V _{GS} (off) | V_{DS} =10V, I_D =1mA | 1.0 | | 2.4 | V |
| Forward Transfer Admittance | yfs | V _{DS} =10V, I _D =7A | 7.7 | 11 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS(on)} 1 | I _D =7A, V _{GS} =10V | | 21 | 28 | mΩ |
| | R _{DS(on)} 2 | I _D =4A, V _{GS} =4.5V | | 29 | 41 | mΩ |

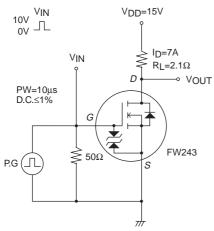
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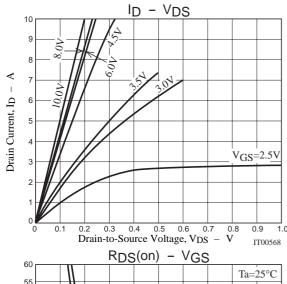
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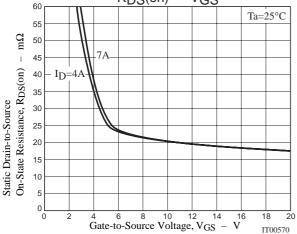
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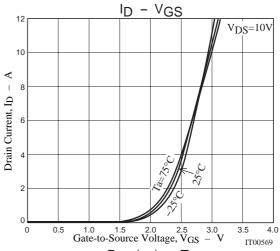
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|--------------------|--|---------|------|-----|------|
| | | | min | typ | max | Oill |
| Input Capacitance | Ciss | V _{DS} =10V, f=1MHz | | 750 | | pF |
| Output Capacitance | Coss | V _{DS} =10V, f=1MHz | | 300 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =10V, f=1MHz | | 120 | | pF |
| Turn-ON Delay Time | t _{d(on)} | See specified Test Circuit | | 10 | | ns |
| Rise Time | t _r | See specified Test Circuit | | 147 | | ns |
| Turn-OFF Delay Time | td(off) | See specified Test Circuit | | 53 | | ns |
| Fall Time | t _f | See specified Test Circuit | | 58 | | ns |
| Total Gate Charge | Qg | V _{DS} =10V, V _{GS} =10V, I _D =7A | | 14 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =10V, V _{GS} =10V, I _D =7A | | 2.5 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =10V, V _{GS} =10V, I _D =7A | | 1.3 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =7A, V _{GS} =0 | | 0.79 | 1.2 | V |

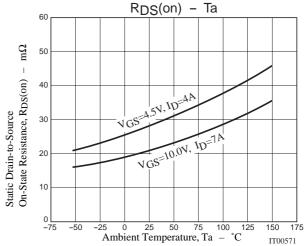
Switching Time Test Circuit

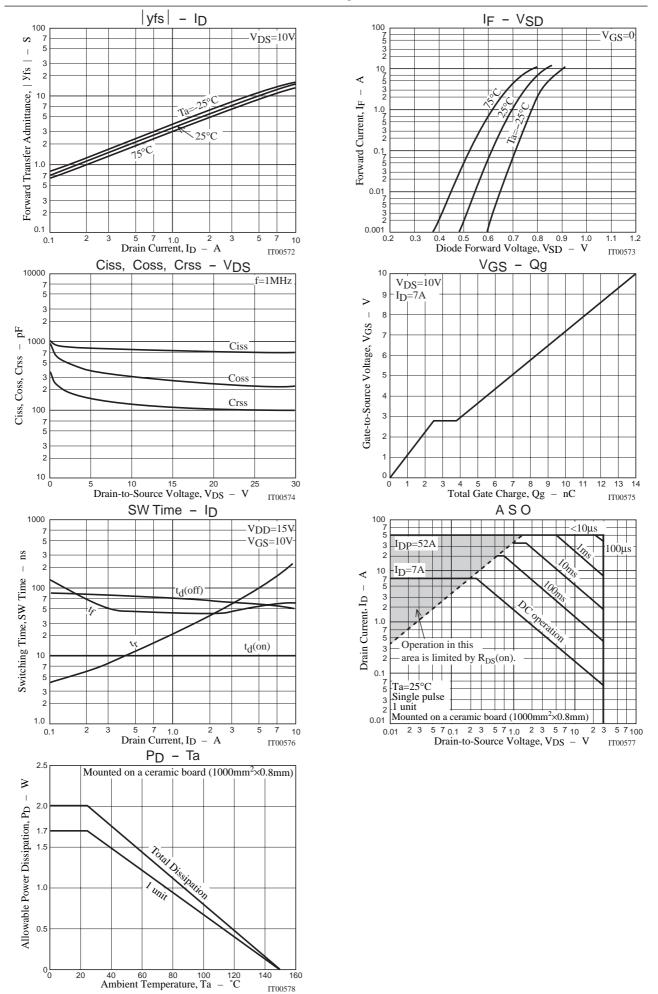












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